

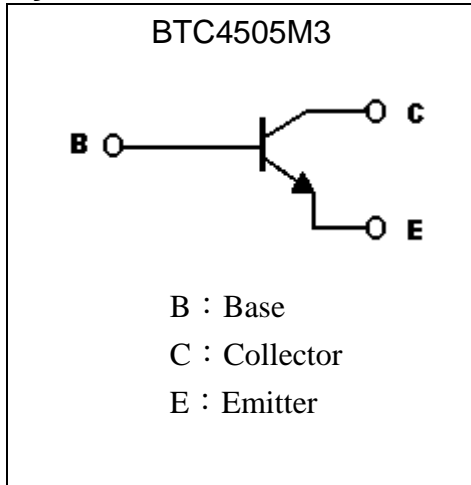
High Voltage NPN Epitaxial Planar Transistor

BTC4505M3

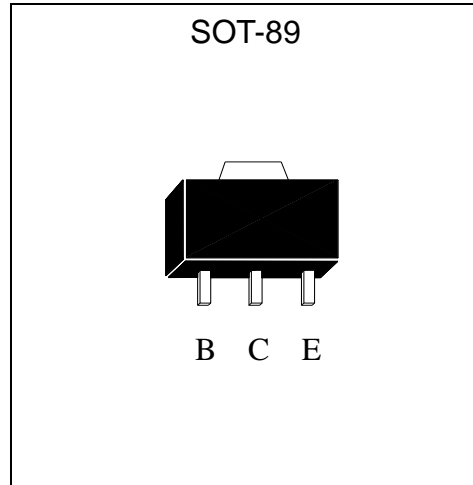
Features

- High breakdown voltage, $BV_{CEO (min)}=400V$.
- Low saturation voltage, typically $V_{CE(sat)}=0.14V$ at $I_C/I_B=50mA/5mA$.
- Complementary to BTA1759M3.
- Pb-free lead plating and halogen-free package.

Symbol

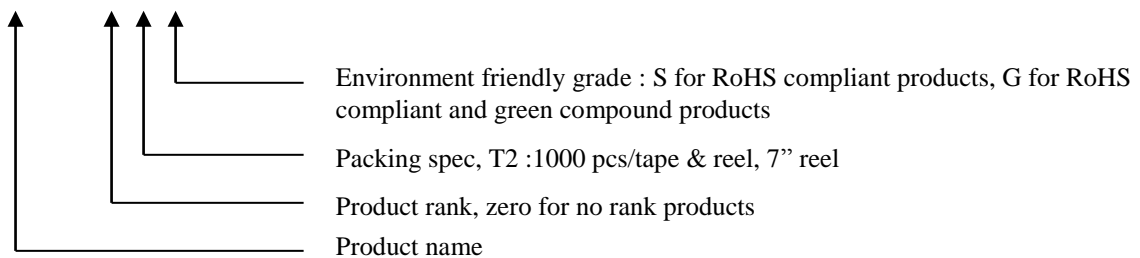


Outline



Ordering Information

Device	Package	Shipping
BTC4505M3-0-T2-G	SOT-89 (Pb-free lead plating and halogen-free package)	1000 pcs / Tape & Reel

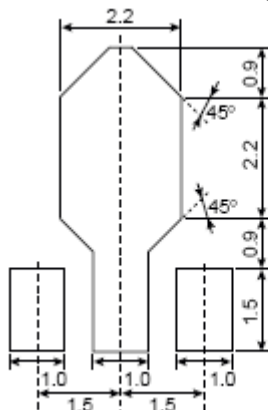


Absolute Maximum Ratings ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V_{CBO}	500	V
Collector-Emitter Voltage	V_{CEO}	400	V
Emitter-Base Voltage	V_{EBO}	6	V
Collector Current	I_C	300	mA
Power Dissipation	P_d	600	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55~+150	$^\circ\text{C}$

Characteristics ($T_a=25^\circ\text{C}$)

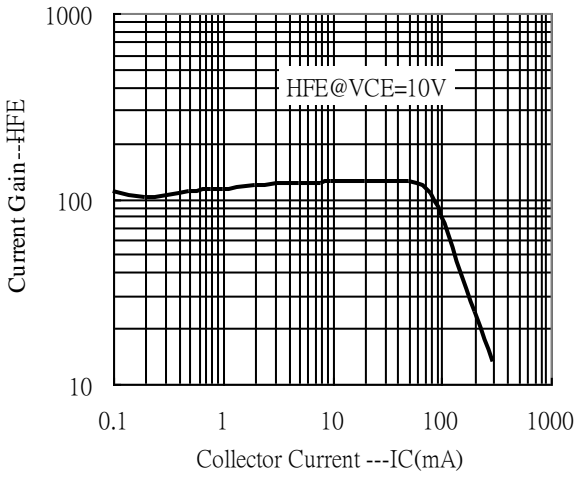
Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV_{CBO}	500	-	-	V	$I_C=50\mu\text{A}, I_E=0$
BV_{CEO}	400	-	-	V	$I_C=1\text{mA}, I_B=0$
BV_{EBO}	6	-	-	V	$I_E=50\mu\text{A}, I_C=0$
I_{CBO}	-	-	100	nA	$V_{CB}=500\text{V}, I_E=0$
I_{CES}	-	-	100	nA	$V_{CE}=500\text{V}, V_{BE}=0$
I_{EBO}	-	-	100	nA	$V_{EB}=6\text{V}, I_C=0$
$V_{CE(sat)}$	-	0.08	0.15	V	$I_C=1\text{mA}, I_B=0.1\text{mA}$
$V_{CE(sat)}$	-	0.08	0.15	V	$I_C=10\text{mA}, I_B=1\text{mA}$
* $V_{CE(sat)}$	-	0.14	0.25	V	$I_C=50\text{mA}, I_B=5\text{mA}$
* $V_{BE(sat)}$	-	0.68	0.75	V	$I_C=10\text{mA}, I_B=1\text{mA}$
h_{FE}	80	-	-	-	$V_{CE}=10\text{V}, I_C=1\text{mA}$
h_{FE}	120	-	270	-	$V_{CE}=10\text{V}, I_C=10\text{mA}$
h_{FE}	100	-	-	-	$V_{CE}=10\text{V}, I_C=50\text{mA}$
h_{FE}	40	-	-	-	$V_{CE}=10\text{V}, I_C=100\text{mA}$
f_T	-	20	-	MHz	$V_{CE}=10\text{V}, I_C=10\text{mA}, f=100\text{MHz}$
Cob	-	7	-	pF	$V_{CB}=10\text{V}, f=1\text{MHz}$

 *Pulse Test : Pulse Width $\leq 380\mu\text{s}$, Duty Cycle $\leq 2\%$
Recommended soldering footprint


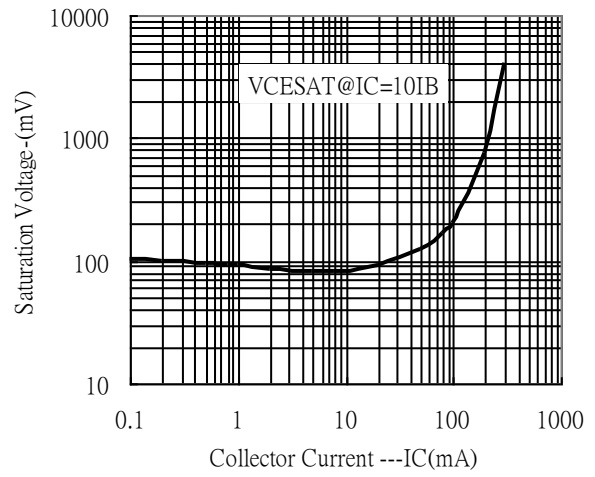
unit : mm

Typical Characteristics

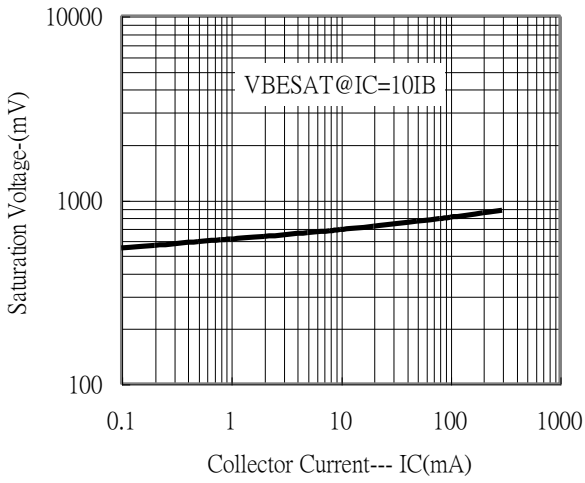
Current Gain vs Collector Current



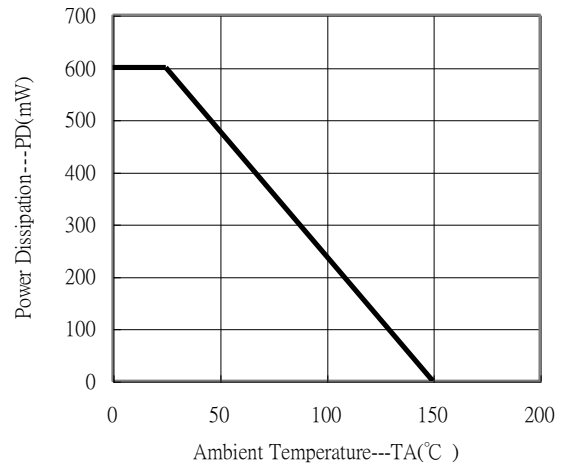
Saturation Voltage vs Collector Current



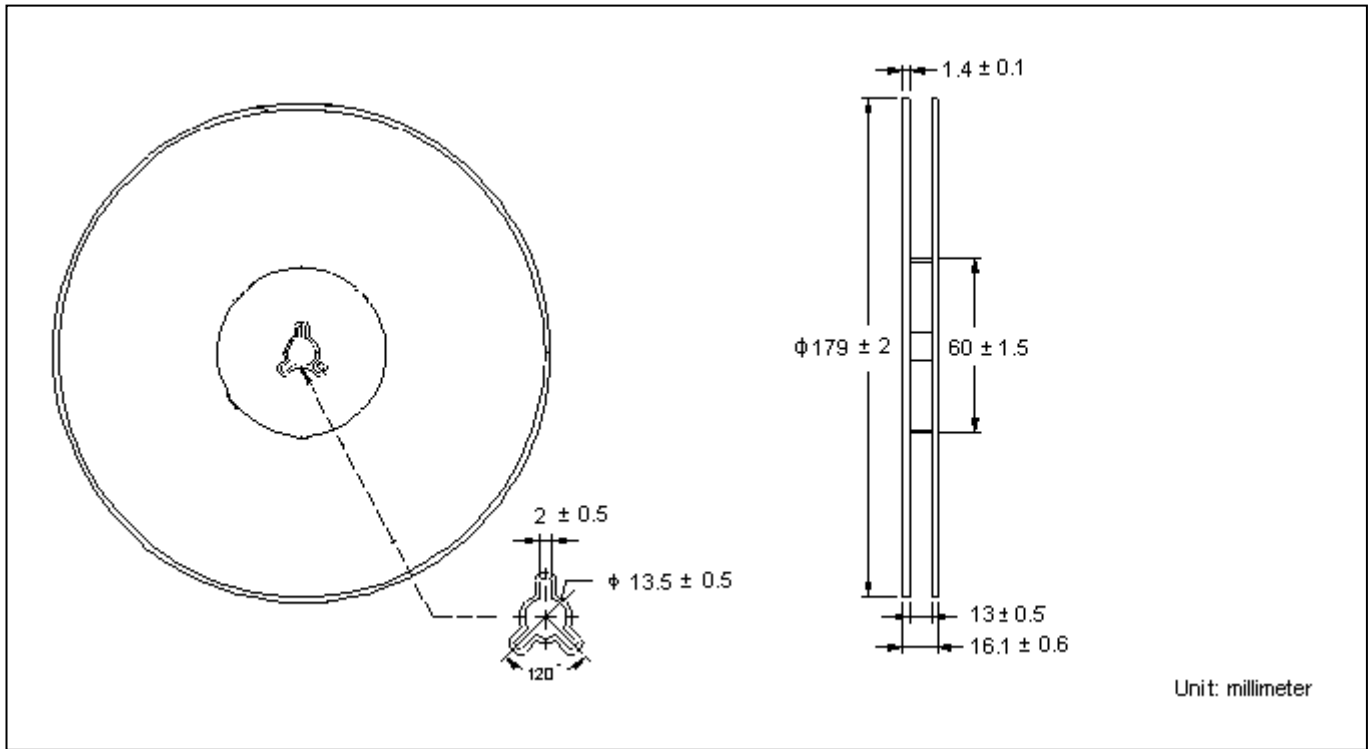
Saturation Voltage vs Collector Current



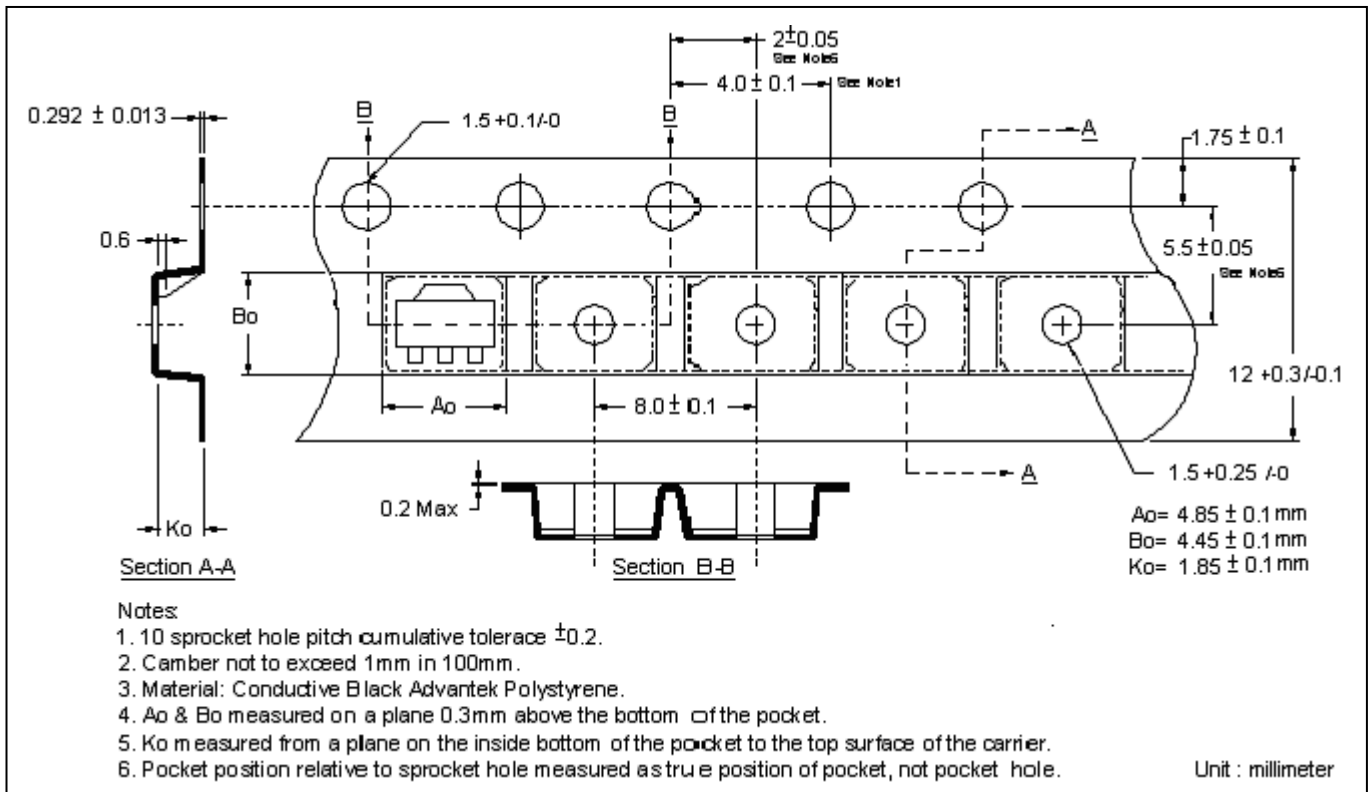
Power Derating Curve



Reel Dimension



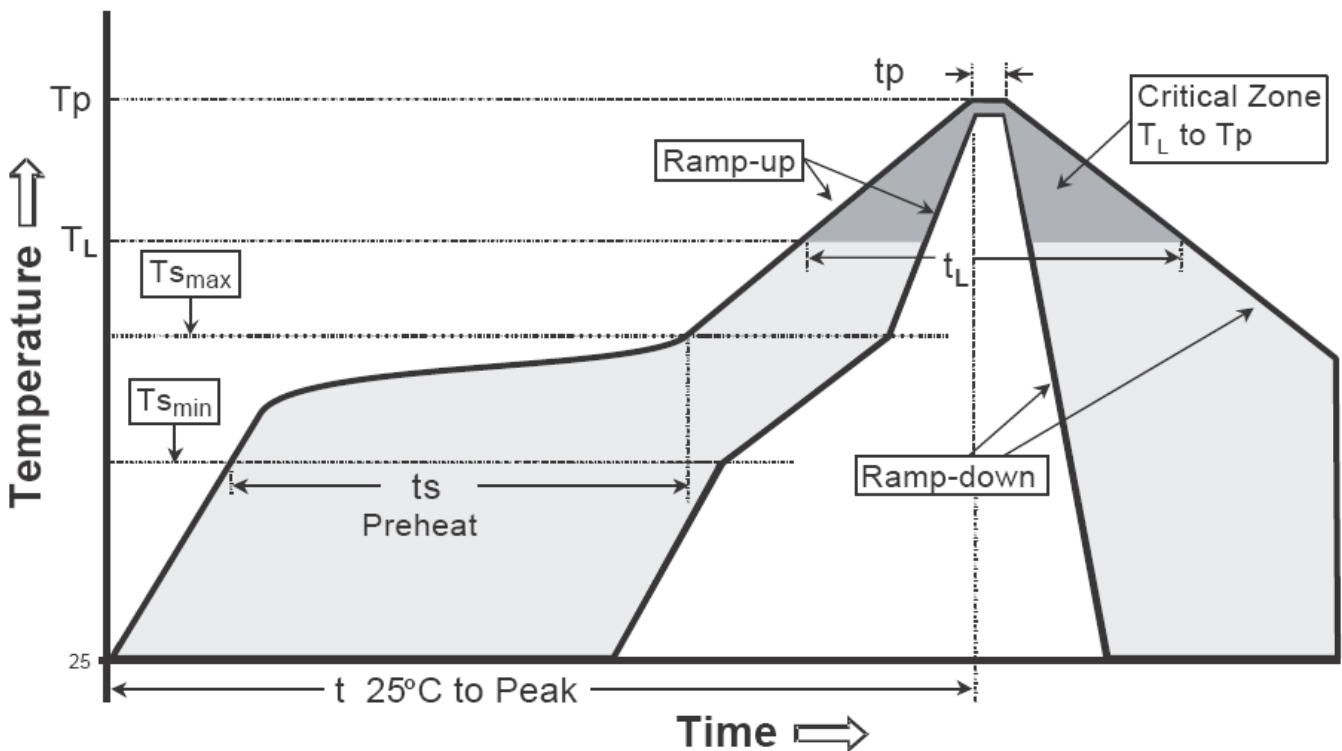
Carrier Tape Dimension



Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

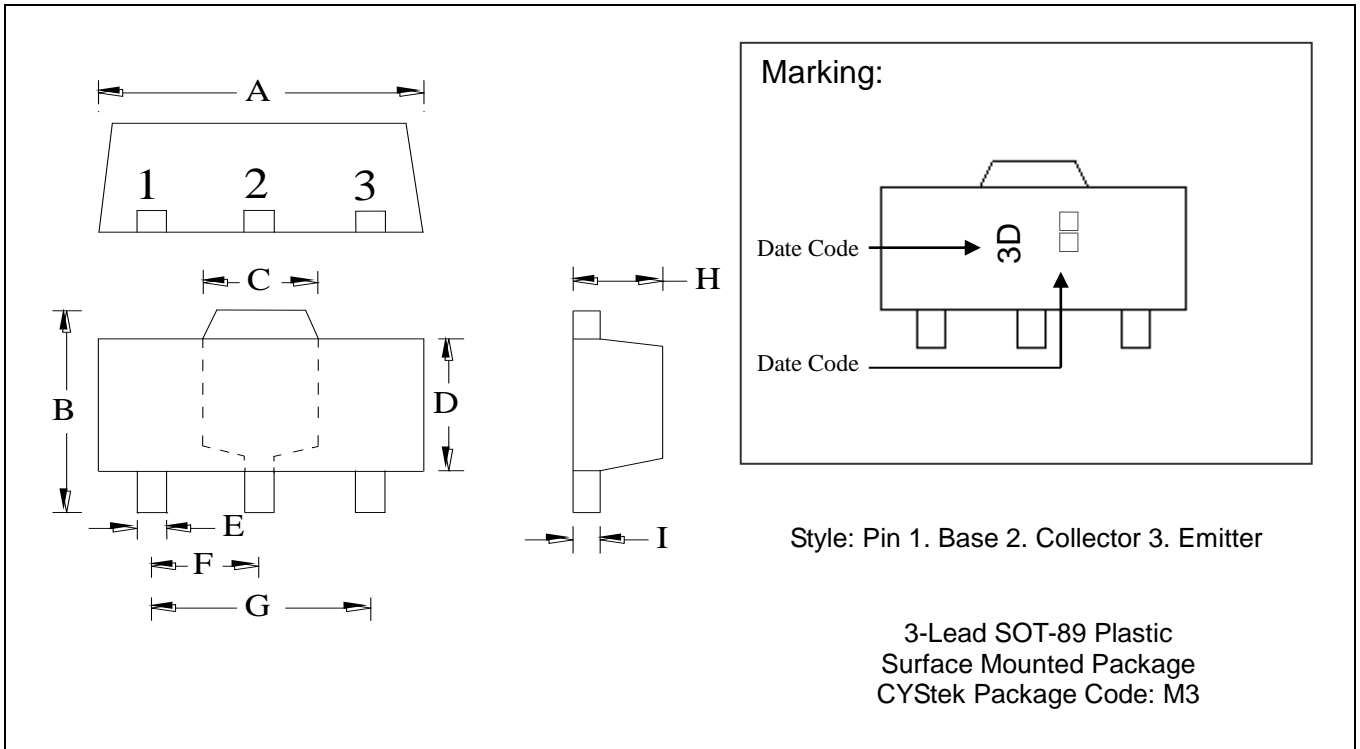
Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (T _{smax} to T _p)	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(T _{s min})	100°C	150°C
-Temperature Max(T _{s max})	150°C	200°C
-Time(t _{s min} to t _{s max})	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (T _L)	183°C	217°C
- Time (t _L)	60-150 seconds	60-150 seconds
Peak Temperature(T _p)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(t _p)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

SOT-89 Dimension



DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1732	0.1811	4.40	4.60	F	0.0591 TYP		1.50 TYP	
B	0.1551	0.1673	3.94	4.25	G	0.1181 TYP		3.00 TYP	
C	0.0610	REF	1.55	REF	H	0.0551	0.0630	1.40	1.60
D	0.0906	0.1024	2.30	2.60	I	0.0138	0.0173	0.35	0.44
E	0.0126	0.0205	0.32	0.52					

Notes: 1.Controlling dimension: millimeters.
 2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

Important Notice:

- All rights are reserved. Reproduction in whole or in part is prohibited without the prior written approval of CYStek.
- CYStek reserves the right to make changes to its products without notice.
- CYStek **semiconductor products are not warranted to be suitable for use in Life-Support Applications, or systems.**
- CYStek assumes no liability for any consequence of customer product design, infringement of patents, or application assistance.